NEC

MOS FIELD EFFECT TRANSISTOR

NP84N055CHE, NP84N055DHE, NP84N055EHE

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

DESCRIPTION

These products are N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE
NP84N055CHE	TO-220AB(MP-25)
NP84N055DHE	TO-262(MP-25 Fin Cut)
NP84N055EHE	TO-263(MP-25ZJ)

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- ★ $R_{DS(on)}$ = 7.3 mΩ MAX. (V_{GS} = 10 V, I_D = 42 A)
- ★ • Low C_{iss} : C_{iss} = 4540 pF TYP.
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

	Drain to Source Voltage	V_{DSS}	55	V
	Gate to Source Voltage	V_{GSS}	±20	V
	Drain Current (DC) Note1	$I_{D(DC)}$	±84	A
	Drain Current (Pulse) Note2	$I_{D(pulse)}$	±336	A
	Total Power Dissipation (T_A = 25°C)	P_T	1.8	W
★	Total Power Dissipation (T_C = 25°C)	P_T	200	W
★	Single Avalanche Current Note3	I_{AS}	84 / 56 / 21	A
★	Single Avalanche Energy Note3	E_{AS}	70 / 313 / 441	mJ
	Channel Temperature	T_{ch}	175	°C
	Storage Temperature	T_{stg}	–55 to +175	°C

Notes 1. Package Limit = ± 75 A

2. PW ≤ 10 μs, Duty cycle ≤ 1 %

3. Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V→0 V

THERMAL RESISTANCE

★	Channel to Case	$R_{th(ch-C)}$	0.75	°C/W
★	Channel to Ambient	$R_{th(ch-A)}$	83.3	°C/W

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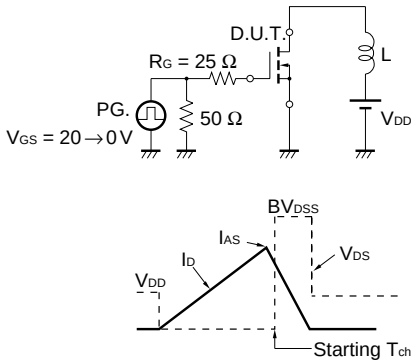
The mark ★ shows major revised points.

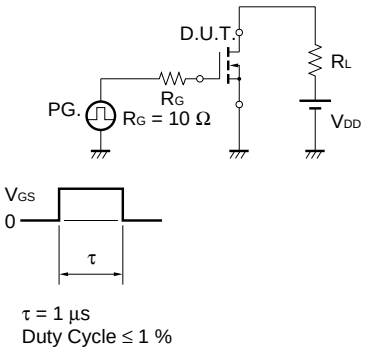
★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 42 A		5.8	7.3	mΩ
Gate to Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 μA	2.0	3	4.0	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 42 A	22	44		S
Drain Leakage Current	I_{DSS}	V_{DS} = 55 V, V_{GS} = 0 V			10	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Input Capacitance	C_{iss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz		4540	6810	pF
Output Capacitance	C_{oss}			710	1070	pF
Reverse Transfer Capacitance	C_{rss}			340	620	pF
Turn-on Delay Time	$t_{d(on)}$	I_D = 42 A, $V_{GS(on)}$ = 10 V, V_{DD} = 28 V,		120	260	ns
Rise Time	t_r	R_G = 10 Ω		1500	3750	ns
Turn-off Delay Time	$t_{d(off)}$			200	390	ns
Fall Time	t_f			260	640	ns
Total Gate Charge	Q_G	I_D = 84 A, V_{DD} = 44 V, V_{GS} = 10 V		88	130	nC
Gate to Source Charge	Q_{GS}			22		nC
Gate to Drain Charge	Q_{GD}			31		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 84 A, V_{GS} = 0 V		1.0		V
Reverse Recovery Time	t_{rr}	I_F = 84 A, V_{GS} = 0 V, di/dt = 100 A/μs		49		ns
Reverse Recovery Charge	Q_{rr}			78		nC

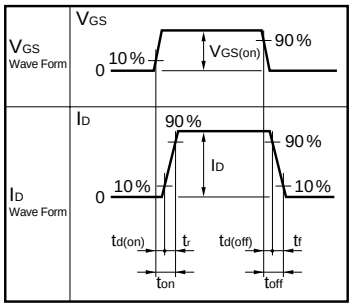
TEST CIRCUIT 1 AVALANCHE CAPABILITY



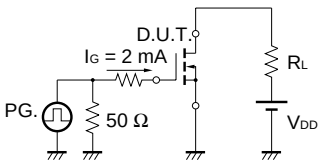
TEST CIRCUIT 2 SWITCHING TIME



τ = 1 μs
Duty Cycle ≤ 1 %

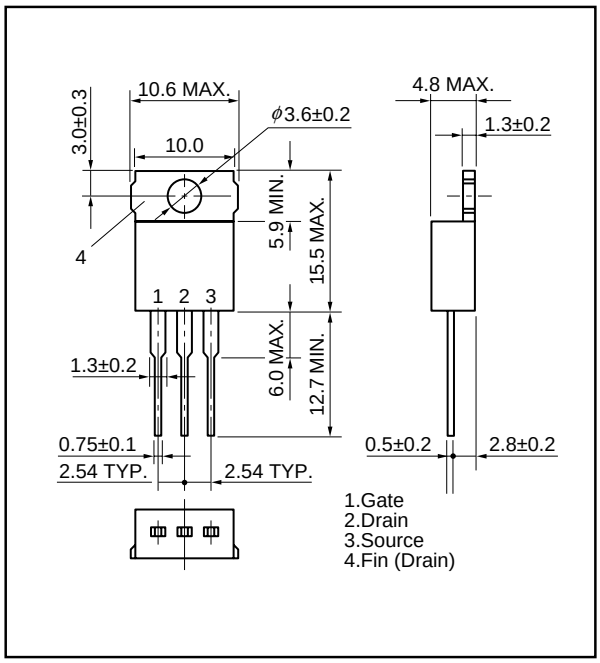


TEST CIRCUIT 3 GATE CHARGE

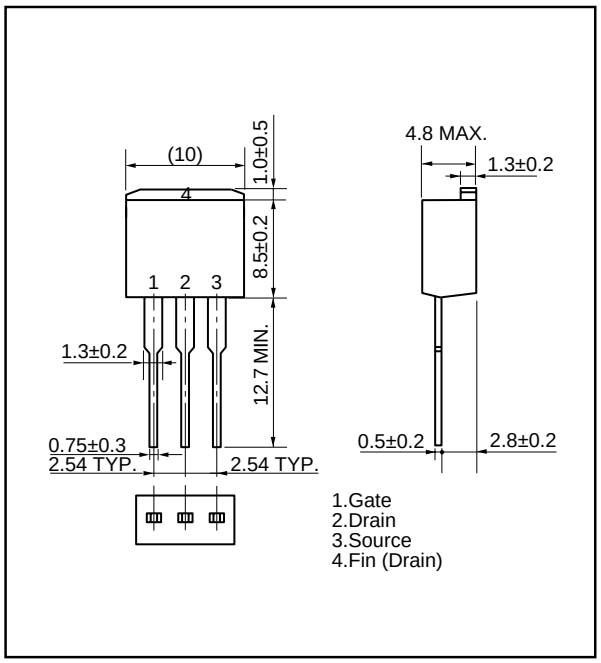


PACKAGE DRAWINGS (Unit: mm)

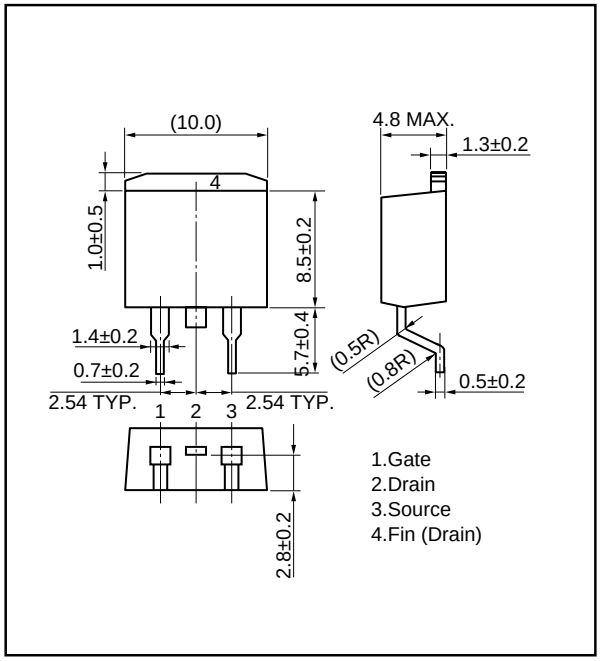
1) TO-220AB (MP-25)



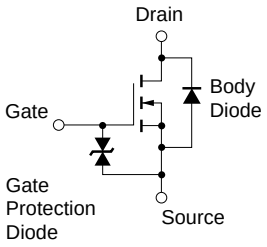
2) TO-262 (MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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